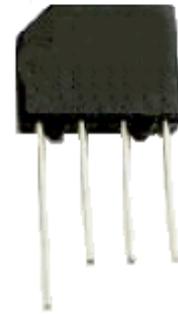


### Features

- Reliable low cost construction utilizing molded plastic technique
- Ideal for printed circuit board
- Low forward voltage drop
- Low reverse leakage current
- High surge current capability
- Glass Passivated Die Construction



KBP

### Mechanical Data

- **Case:** Molded plastic, KBP
- **Epoxy:** UL 94V-O rate flame retardant
- **Terminals:** Leads solderable per MIL-STD-202, method 208 guaranteed
- **Mounting Position:** Any
- **Weight:** 0.012ounce, 0.33gram

### Major Ratings and Characteristics

$I_{F(AV)}$	2.0 A
$V_{RRM}$	50 V to 1000 V
$I_{FSM}$	60 A
$V_F$	1.1 V
$T_J \text{ max.}$	150 °C

### Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60HZ, resistive or inductive load.

For capacitive load, derate current by 20%.

Items	Symbols	KBP 2005G	KBP 201G	KBP 202G	KBP 204G	KBP 206G	KBP 208G	KBP 210G	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	500	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at $T_A=50^\circ\text{C}$	$I_{(AV)}$	2.0							A
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	$I_{FSM}$	60							A
Typical thermal resistance per leg <sup>(1)</sup>	$R_{\theta JA}$	30							°C/W
Typical thermal resistance per leg <sup>(1)</sup>	$R_{\theta JC}$	11							N·m
Operating junction temperature range	$T_J$	-55 to +150							°C
Storage temperature range	$T_{STG}$	-55 to +150							°C

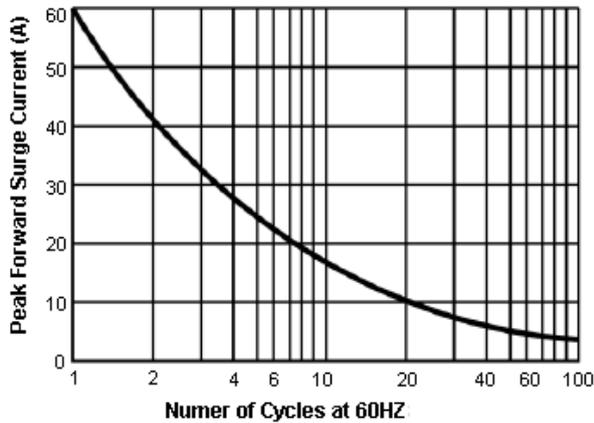
Note 1: Thermal Resistance Junction to Ambient and from junction to lead at 0.375"(9.5mm) lead length P.C.B. Mounted.

### Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

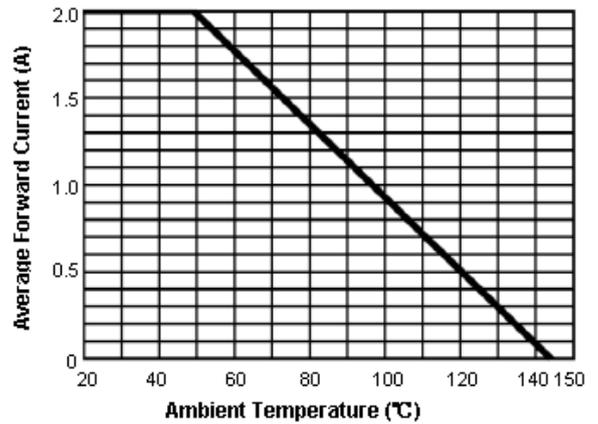
Items	Test conditions	Symbol	Min	Type	Max	UNIT
Instantaneous forward voltage	$I_F=2.0A$	$V_F$	-	-	1.1	V
Reverse current	$V_R=V_{DC}$ $T_J=25^\circ\text{C}$ $T_J=125^\circ\text{C}$	$I_R$	-	-	10.0 500	$\mu\text{A}$
Typical Junction Capacitance	4.0 V ,1MHz	$C_J$	-	25.00	-	V

## Characteristic Curves (T<sub>A</sub>=25 °C unless otherwise noted)

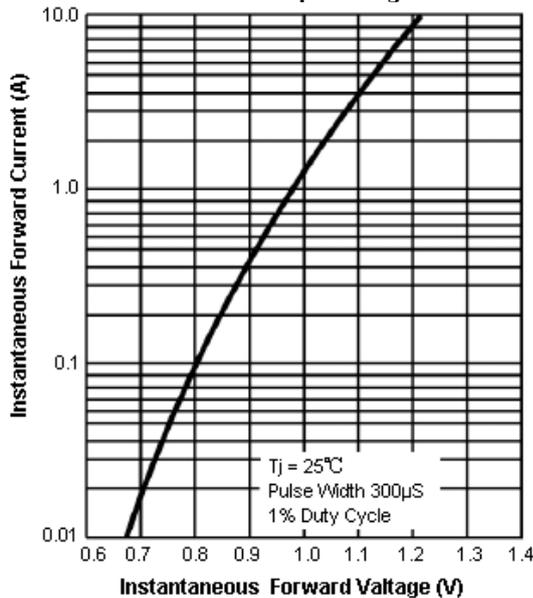
**FIG.1 Maximum Non-repetitive Forward Surge Current per Bridge Element**



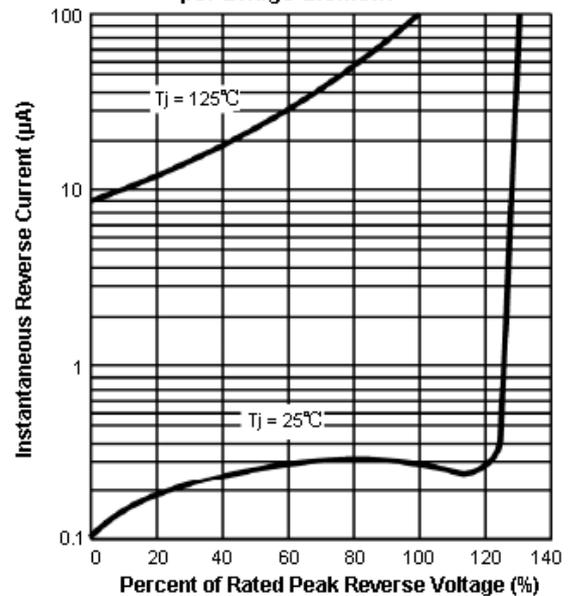
**FIG.2 Maximum Forward Current Derating Curve**



**FIG.3 Typical Instantaneous Forward Characteristics per Bridge Element**



**FIG.4 Typical Reverse Characteristics per Bridge Element**



### Package Outline

